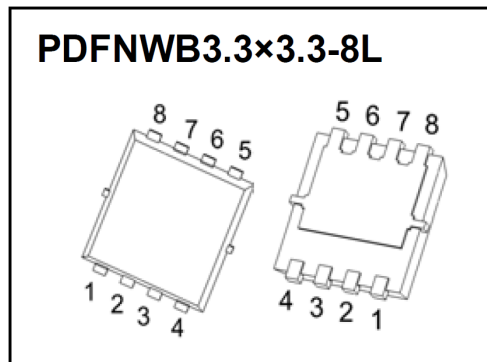


CJAB25P03A P-Channel Power MOSFET

$V_{(BR)DSS}$	$R_{DS(on)}$ TYP	I_D
-30V	13mΩ@-10V	-25A
	17mΩ@-4.5V	



DESCRIPTION

The CJAB25P03A uses advanced trench technology and design to provide excellent $R_{DS(on)}$ with low gate charge. It can be used in a wide variety of applications.

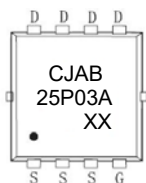
FEATURE

- High density cell design for ultra-low $R_{DS(on)}$
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation

APPLICATIONS

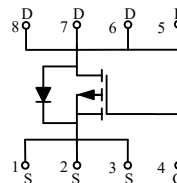
- Battery and loading switching

MARKING



CJAB25P03A = Part No.
 Solid dot=Pin1 indicator
 XX=Date Code

EQUIVALENT CIRCUIT



Maximum ratings ($T_a=25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	-30	V
Gate-Source Voltage	V_{GS}	±20	V
Continuous Drain Current	$I_D^{(1)}$	-25	A
Pulsed Drain Current	$I_{DM}^{(2)}$	-100	A
Single Pulsed Avalanche Energy	$E_{AS}^{(3)}$	100	mJ
Power Dissipation	$P_D^{(1)}$	42	W
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-55~+150	°C

Thermal Characteristics

Parameter	Symbol	Typ	Max	Unit
Thermal Resistance from Junction to Ambient	$R_{\theta JA}^{(4)}$	54	81	°C/W
Thermal Resistance from Junction to Case	$R_{\theta JC}^{(1)}$	2.0	3.0	°C/W

MOSFET ELECTRICAL CHARACTERISTICS

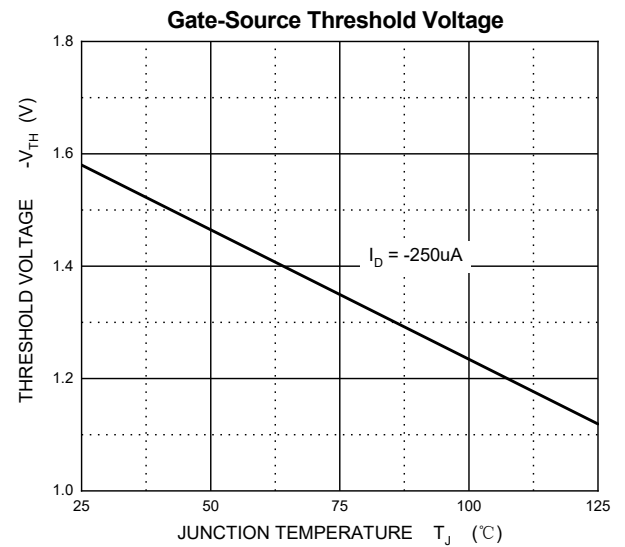
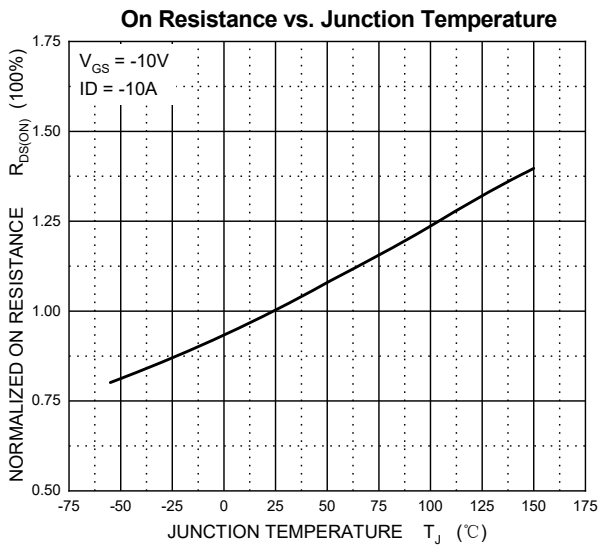
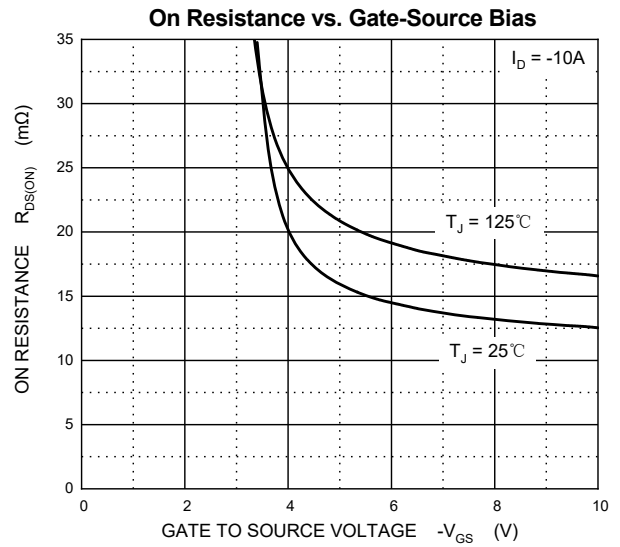
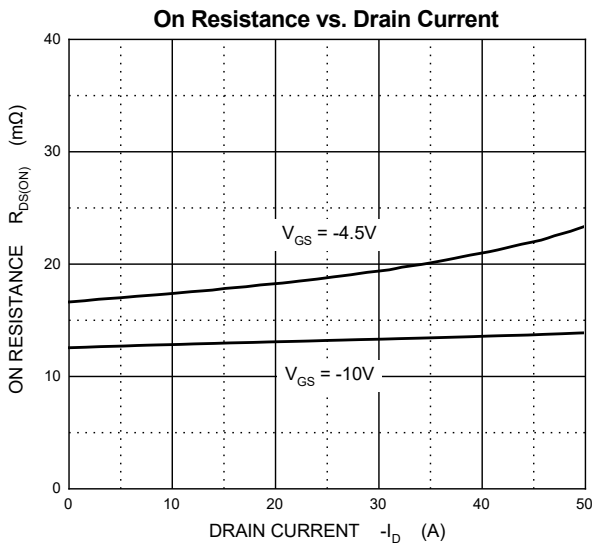
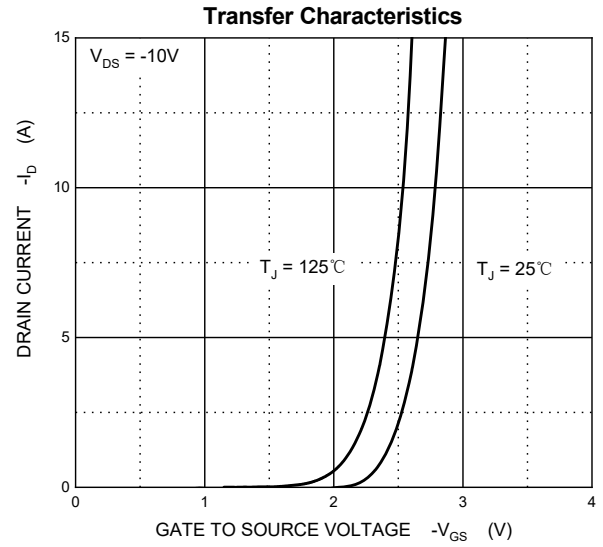
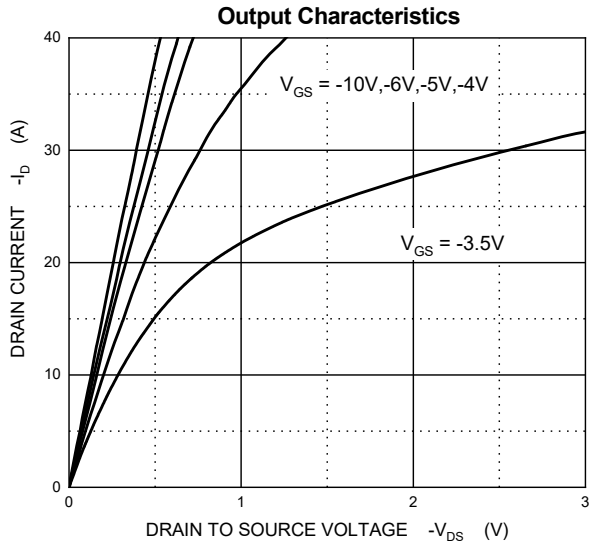
$T_J=25^{\circ}\text{C}$ unless otherwise specified

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Off Characteristics						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=-250\mu A$	-30	-	-	V
Zero gate voltage drain current	I_{DSS}	$V_{DS}=-24V, V_{GS}=0V$	-	-	-1	μA
Gate-body leakage current	I_{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	± 100	nA
On Characteristics ^④						
Gate-threshold voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-1.0	-1.6	-3.0	V
Drain-source on-resistance	$R_{DS(on)}$	$V_{GS}=-10V, I_D=-10A$	-	13	20	m Ω
		$V_{GS}=-4.5V, I_D=-10A$	-	17	30	m Ω
Forward transconductance	g_{FS}	$V_{DS}=-5V, I_D=-10A$	-	43	-	S
Dynamic Characteristics ^⑤						
Input capacitance	C_{iss}	$V_{DS}=-15V, V_{GS}=0V,$ $f=1\text{MHz}$	-	1623	-	pF
Output capacitance	C_{oss}		-	198	-	
Reverse transfer capacitance	C_{rss}		-	144	-	
Switching Characteristics ^⑤						
Total gate charge	Q_g	$V_{DS}=-15V, I_D=-10A,$ $V_{GS}=-10V$	-	29.4	-	nC
Gate-source charge	Q_{gs}		-	5.7	-	
Gate-drain charge	Q_{gd}		-	6.4	-	
Turn-on delay time	$t_{d(on)}$	$V_{DD}=-15V, I_D=-1A,$ $R_L=15\Omega, V_{GS}=-10V,$ $R_G=2.5\Omega$	-	5.4	-	ns
Turn-on rise time	t_r		-	2.6	-	
Turn-off delay time	$t_{d(off)}$		-	87.1	-	
Turn-off fall time	t_f		-	32.4	-	
Drain-Source Diode Characteristics						
Drain-source diode forward voltage	$V_{SD}^{①}$	$V_{GS}=0V, I_S=-10A$	-	-0.85	-1.2	V
Continuous drain-source diode forward current	$I_S^{①}$		-	-	-25	A
Pulsed drain-source diode forward current	$I_{SM}^{②}$		-	-	-100	A

Notes:

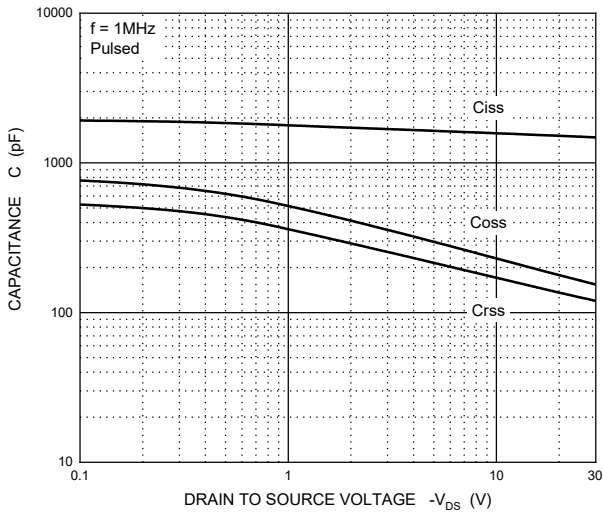
- $T_C=25^{\circ}\text{C}$. Limited only by maximum temperature allowed.
- $P_W \leq 10\mu\text{s}$. Limited only by maximum temperature allowed.
- E_{AS} condition: $V_{DD}=-15V, L=0.5\text{mH}, R_g=25\Omega$ Starting $T_J = 25^{\circ}\text{C}$.
- Pulse Test: Pulse Width $\leq 400\mu\text{s}$, duty cycle $\leq 2\%$.
- Guaranteed by design, not subject to production.
- The value of $R_{\theta JA}$ is measured with the device mounted on 1 in² FR-4 board with 2oz. Copper, in a still air environment with $T_a=25^{\circ}\text{C}$.

Typical Characteristics

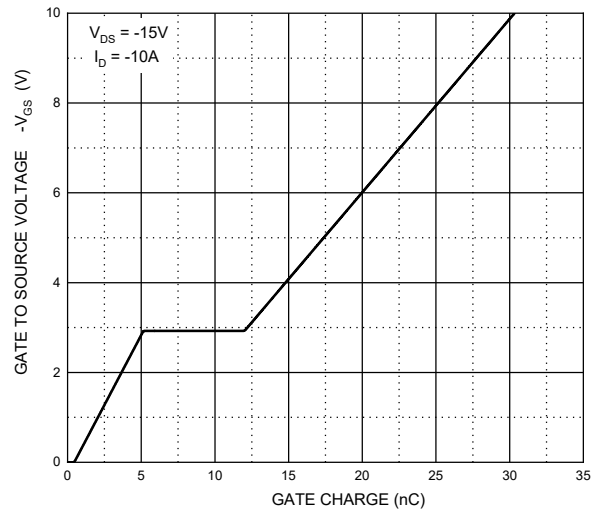


Typical Characteristics

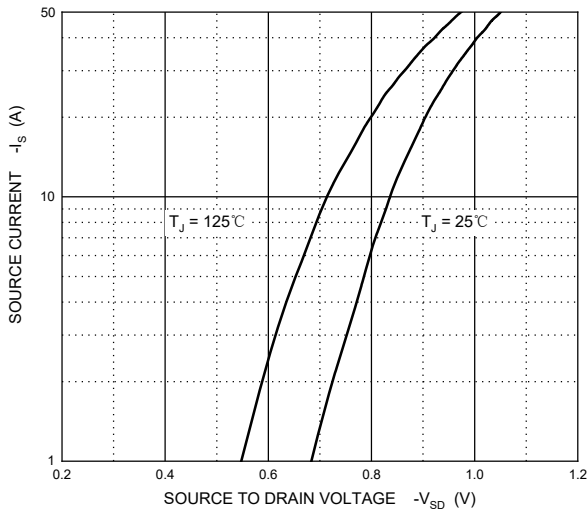
Typical Capacitances



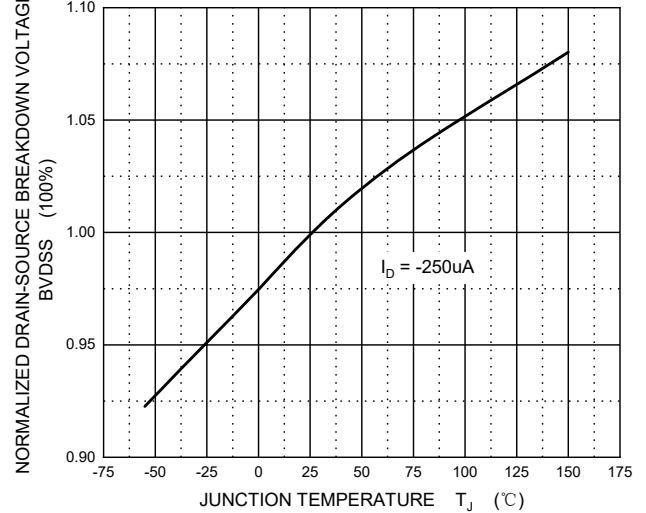
Gate Charge



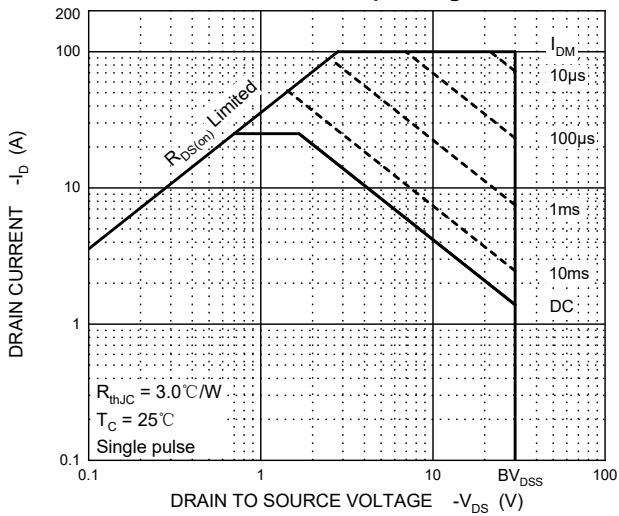
Source-Drain Diode Forward Characteristics



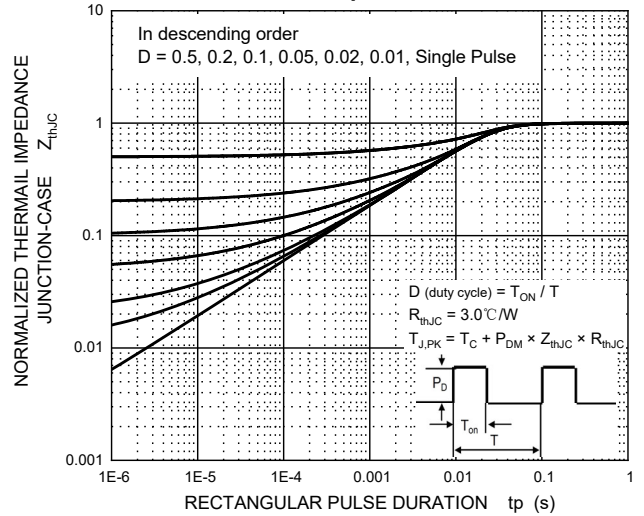
Drain-Source Breakdown Voltage



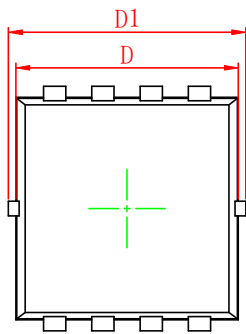
Maximum Safe Operating Area



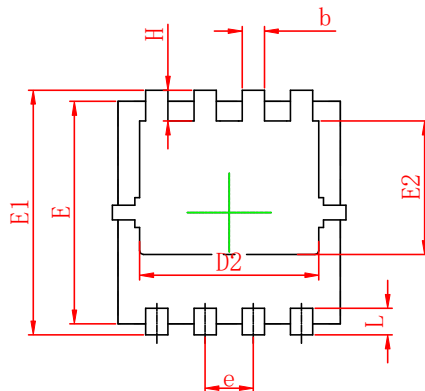
Transient Thermal Impedance, Junction-Case



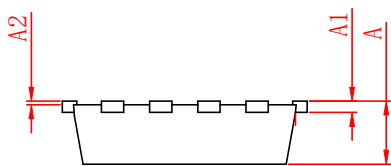
PDFNWB3.3×3.3-8L PACKAGE OUTLINE DIMENSIONS



Top View
[顶视图]



Bottom View
[背视图]



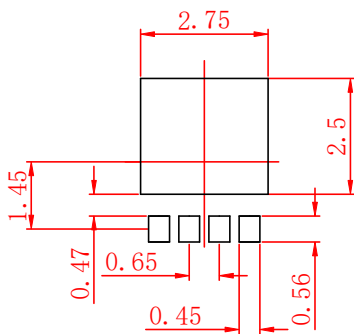
Side View
[侧视图]

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.65	0.90	0.026	0.035
A1	0.15 REF.		0.006 REF.	
A2	0~0.05		0~0.002	
D	2.90	3.20	0.114	0.126
D1	3.00	3.40	0.118	0.134
D2	2.30	2.70	0.091	0.106
E	2.90	3.20	0.114	0.126
E1	3.00	3.40	0.118	0.134
E2	1.60	1.90	0.063	0.075
b	0.20	0.42	0.008	0.017
e	0.65 BSC.		0.026 BSC.	
L	0.20	0.50	0.008	0.020
H	0.32	0.52	0.012	0.020

Notes:

- 1 Dimensions exclusive of mold gate burrs.
- 2 Dimensions exclusive of mold flash and cutting burrs.

PDFNWB3.3×3.3-8L Suggested Pad Layout



Notes:

- 1 Controlling dimension: in millimeters.
- 2 General tolerance: ±0.05mm.
- 2 The pad layout is for reference purpose only.

NOTICE

JSCJ reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. JSCJ does not assume any liability arising out of the application or use of any product described herein.

PDFNWB3.3×3.3-8L Tape and Reel

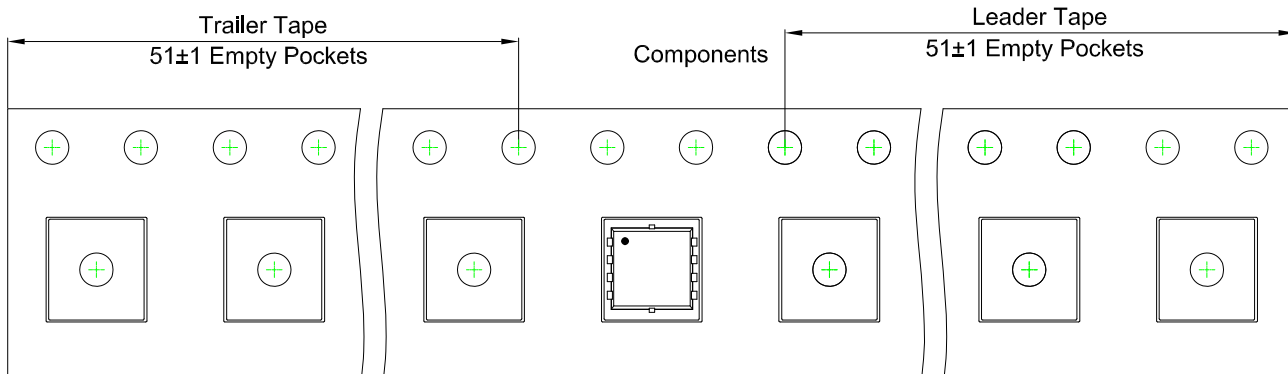
PDFNWB3.3×3.3-8L Embossed Carrier Tape



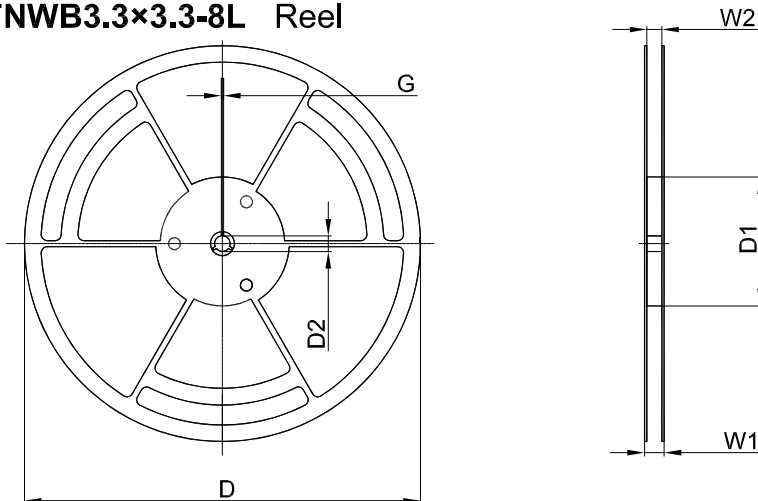
Packaging Description:
PDFNWB3.3x3.3-8L parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 5,000 units per 13" or 33.0 cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
PDFNWB3.3×3.3-8L	3.55	3.55	1.10	Ø1.50	1.75	5.50	4.00	8.00	2.00	12.00

PDFNWB3.3×3.3-8L Tape Leader and Trailer



PDFNWB3.3×3.3-8L Reel



Dimensions are in millimeter						
Reel Option	D	D1	D2	G	W1	W2
13" Dia	φ330.00	100.00	13.00	1.90	17.60	12.40

Reel	Reel Size	Box	Box Size (mm)	Carton	Carton Size (mm)
5,000 pcs	13 inch	10,000 pcs	360×360×65	50,000 pcs	378×358×382